



1200V/40A Silicon Carbide Power Schottky Barrier Diode

Features

- Rated to 1200V at 40 Amps
- Zero reverse recovery current
- Zero forward recovery voltage
- Temperature independent switching behaviour
- High temperature operation
- High frequency operation

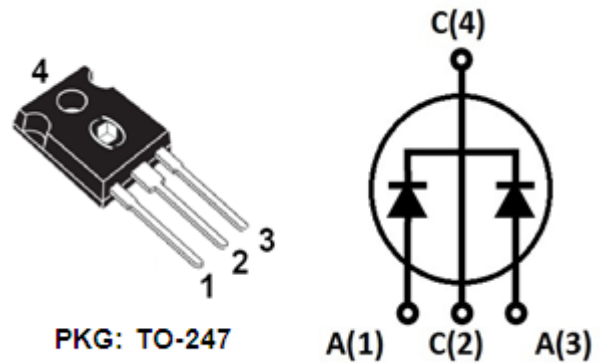
Key Characteristics		
V_{RRM}	1200	V
$I_F, T_c \leq 150^\circ\text{C}$	20*	A
Q_c	161*	nC

Benefits

- Unipolar rectifier
- Substantially reduced switching losses
- No thermal run-away with parallel devices
- Reduced heat sink requirements

Applications

- SMPS, e.g., CCM PFC;
- Motor drives, Solar application, UPS, Wind turbine, Rail traction, EV/HEV



Part No.	Package Type	Marking
G3S12040B	TO-247AB	G3S12040B

* Per leg ; ** per device

Maximum Ratings

Parameter	Symbol	Test Condition	Value	Unit
Repetitive Peak Reverse Voltage	V_{RRM}		1200	V
Surge Peak Reverse Voltage	V_{RSM}		1200	V
DC Blocking Voltage	V_{DC}		1200	V
Continuous Forward Current	I_F	$T_C=25^{\circ}C$ $T_C=135^{\circ}C$ $T_C=155^{\circ}C$	64.5* 35.2* 20*	A
Repetitive Peak Forward Surge Current	I_{FRM}	$T_C=25^{\circ}C$, $t_p=10ms$, Half Sine Wave, $D=0.3$	100*	A
Non-repetitive Peak Forward Surge Current	I_{FSM}	$T_C=25^{\circ}C$, $t_p=10ms$, Half Sine Wave	270*	A
Power Dissipation	P_{TOT}	$T_C=25^{\circ}C$	357*	W
		$T_C=110^{\circ}C$	155*	W
Operating Junction	T_j		-55°C to 175°C	°C
Storage Temperature	T_{stg}		-55°C to 175°C	°C
Mounting Torque		M3 Screw	1	Nm
		6-32 Screw	8.8	lbf-in

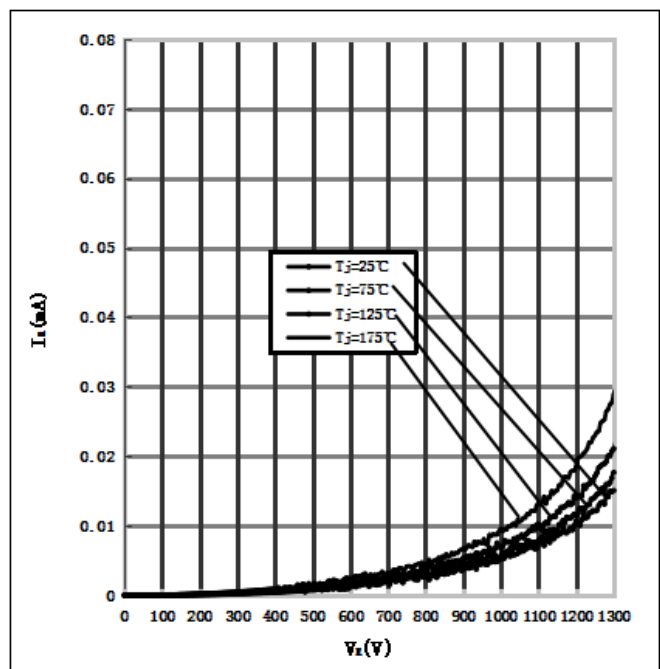
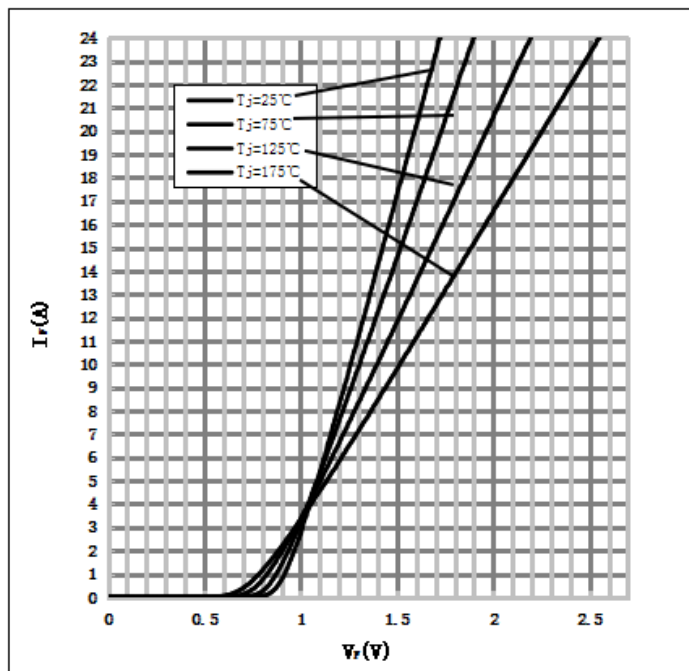
Thermal Characteristics

Parameter	Symbol	Test Condition	Value	Unit
			Typ.	
Thermal resistance from junction to case	$R_{th JC}$		0.42* 0.21**	°C/W

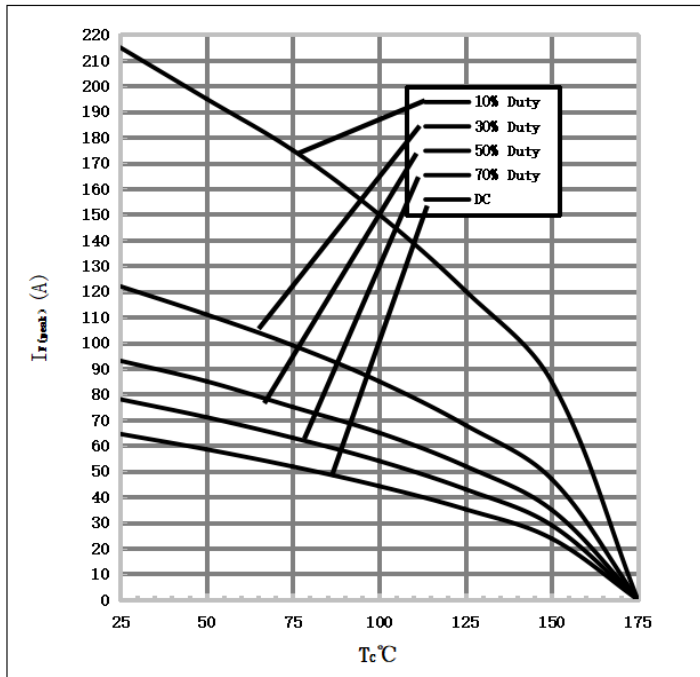
* Per leg ; ** per device

Electrical Characteristics(Per leg)

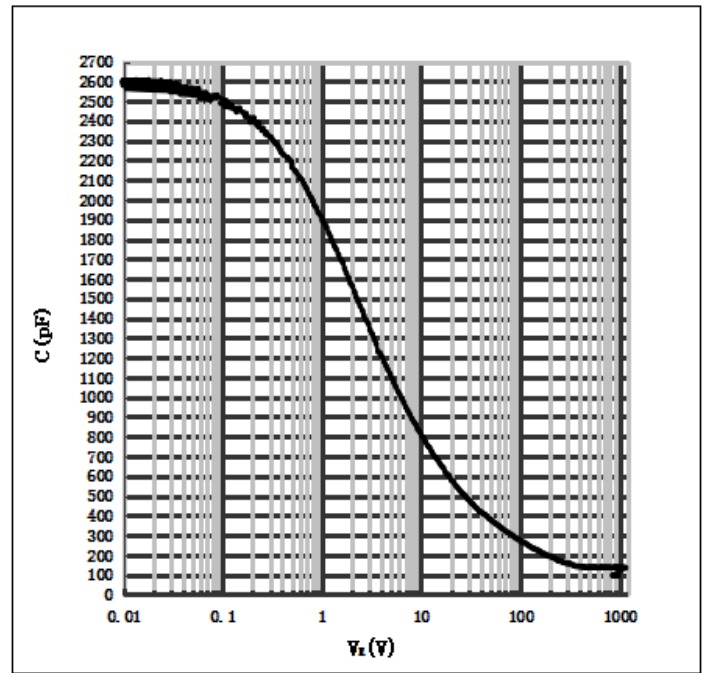
Parameter	Symbol	Test Conditions	Numerical		Unit
			Typ.	Max.	
Forward Voltage	V_F	$I_F=15A, T_j=25^\circ C$	1.45	1.7	V
		$I_F=15A, T_j=175^\circ C$	2.2	2.5	
Reverse Current	I_R	$V_R=1200V, T_j=25^\circ C$	15	50	μA
		$V_R=1200V, T_j=175^\circ C$	25	100	
Total Capacitive Charge	Q_C	$V_R=800V, T_j=150^\circ C$ $Q_C = \int_0^{VR} C(V)dV$	161	-	nC
Total Capacitance	C	$V_R=0V, T_j=25^\circ C, f=1MHZ$	2600	2700	pF
		$V_R=400V, T_j=25^\circ C, f=1MHZ$	140	145	
		$V_R=800V, T_j=25^\circ C, f=1MHZ$	137	140	

Performance Graphs1) Forward IV characteristics as a function of T_j :2) Reverse IV characteristics as a function of T_j :

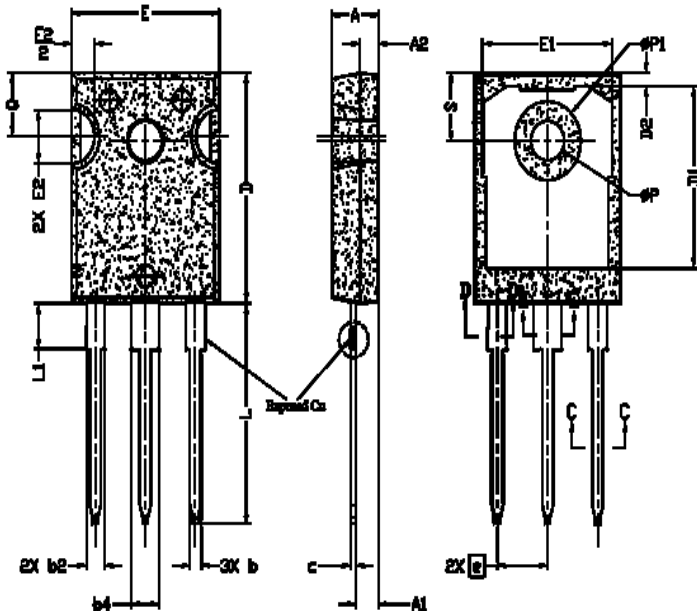
3) Current Derating



4) Capacitance vs. reverse voltage :



Package TO-247AB



SYMBOL	DIMENSIONS			NOTES
	MIN	NOM	MAX	
A	4.83	5.02	5.21	
A1	2.29	2.41	2.55	
A2	1.50	2.00	2.49	
b	1.12	1.20	1.33	
b1	1.12	1.20	1.28	
b2	1.91	2.00	2.39	6
b3	1.91	2.00	2.34	
b4	2.87	3.00	3.22	6, 8
b5	2.87	3.00	3.18	
c	0.55	0.60	0.69	6
c1	0.55	6.00	0.65	
D	20.80	20.95	21.10	4
D1	16.25	16.55	17.65	5
D2	0.51	1.19	1.35	
E	15.75	15.94	16.13	4
E1	13.46	14.02	14.16	5
E2	4.32	4.91	5.49	3
e	5.44 BSC			
L	19.81	20.07	20.32	
L1	4.10	4.19	4.40	6
ΦP	3.56	3.61	3.65	7
ΦP1	7.19 REF			
Q	5.39	5.79	6.20	
S	6.04	6.17	6.30	

Note: The levels of RoHS restricted materials in this product are below the maximum concentration values (also referred to as the threshold limits) permitted for such substances, or are used in an exempted application, in accordance with EU Directive 2011/65/EC(RoHS2). RoHS Certification and other certifications can be obtained from GPT sales representatives or GPT website: <http://globalpowertech.cn/English/index.asp>

More product datasheets and company information can be found in:

<http://globalpowertech.cn/English/index.asp>

